## FEATURES

Latch-up immune under all circumstances Human body model (HBM) ESD rating: $\mathbf{8 k V}$<br>Low on resistance: $13.5 \Omega$<br>$\pm 9 \mathrm{~V}$ to $\pm 22 \mathrm{~V}$ dual-supply operation<br>9 V to 40 V single-supply operation<br>48 V supply maximum ratings<br>Fully specified at $\pm 15 \mathrm{~V}, \pm 20 \mathrm{~V},+12 \mathrm{~V}$, and $+\mathbf{3 6} \mathrm{V}$<br>$\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{ss}}$ analog signal range

## APPLICATIONS

High voltage signal routing
Automatic test equipment
Analog front-end circuits
Precision data acquisition
Industrial instrumentation
Amplifier gain select
Relay replacement

## GENERAL DESCRIPTION

The ADG5419 is a monolithic industrial, complementary metal oxide semiconductor (CMOS) analog switch containing a latchup immune single-pole/double-throw (SPDT) switch.

Each switch conducts equally well in both directions when on, and each switch has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked. The ADG5419 exhibits break-before-make switching action for use in multiplexer applications.
The ultralow on resistance and on-resistance flatness of these switches make them ideal solutions for data acquisition and gain switching applications where low distortion is critical. The latch-up immune construction and high ESD rating make these switches more robust in harsh environments.

## FUNCTIONAL BLOCK DIAGRAM



SWITCHES SHOWN FOR A LOGIC 0 INPUT. $\stackrel{\stackrel{\circ}{\mathrm{m}}}{\stackrel{\circ}{+}}$
Figure 1.

## PRODUCT HIGHLIGHTS

1. Trench isolation guards against latch-up. A dielectric trench separates the P channel and N channel transistors, thereby preventing latch-up even under severe overvoltage conditions.
2. Low R ${ }_{\text {on }}$ of $13.5 \Omega$.
3. Dual-supply operation. For applications where the analog signal is bipolar, the ADG5419 can be operated from dual supplies up to $\pm 22 \mathrm{~V}$.
4. Single-supply operation. For applications where the analog signal is unipolar, the ADG5419 can be operated from a single-rail power supply up to 40 V .
5. 3 V logic compatible digital inputs: $\mathrm{V}_{\mathrm{INH}}=2.0 \mathrm{~V}, \mathrm{~V}_{\text {INL }}=0.8 \mathrm{~V}$.
6. No $V_{L}$ logic power supply required.
7. Available in 8-lead MSOP package.

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## REVISION HISTORY

9/13-Revision 0: Initial Version

## SPECIFICATIONS

$\pm 15$ V DUAL SUPPLY
$\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-15 \mathrm{~V} \pm 10 \%$, GND $=0 \mathrm{~V}$, unless otherwise noted.
Table 1.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH <br> Analog Signal Range On Resistance, Ron <br> On-Resistance Match Between Channels, $\Delta$ Ron <br> On-Resistance Flatness, Relat (on) | $\begin{aligned} & 13.5 \\ & 15 \\ & 0.1 \\ & 0.8 \\ & 1.8 \\ & 2.2 \\ & \hline \end{aligned}$ | 19 <br> 1.3 $2.7$ | $\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{SS}}$ <br> 23 <br> 1.4 <br> 3.1 | V <br> $\Omega$ typ <br> $\Omega$ max <br> $\Omega$ typ <br> $\Omega$ max <br> $\Omega$ typ <br> $\Omega$ max | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} ; \text { see Figure } 22 \\ & \mathrm{~V}_{\mathrm{DD}}=+13.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-13.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} \end{aligned}$ $\mathrm{V}_{\mathrm{s}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) <br> Channel On Leakage, Io (On), Is (On) | $\begin{aligned} & \pm 0.1 \\ & \pm 0.25 \\ & \pm 0.1 \\ & \pm 0.4 \end{aligned}$ | $\pm 1$ $\pm 4$ | $\begin{aligned} & \pm 10 \\ & \pm 10 \\ & \hline \end{aligned}$ | nA typ <br> nA max <br> nA typ <br> nA max | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-16.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 10 \mathrm{~V} \text {; see Figure } 21 \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}= \pm 10 \mathrm{~V} \text {; see Figure } 21 \end{aligned}$ |
| DIGITAL INPUTS Input High Voltage, $\mathrm{V}_{\mathrm{NH}}$ Input Low Voltage, $\mathrm{V}_{\mathrm{INL}}$ Input Current, $\mathrm{I}_{\text {INL }}$ or $\mathrm{l}_{\text {INH }}$ <br> Digital Input Capacitance, $\mathrm{C}_{\mathrm{IN}}$ | $0.002$ |  | $\begin{aligned} & 2.0 \\ & 0.8 \\ & \pm 0.1 \end{aligned}$ | $V$ min <br> $\checkmark$ max <br> $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> pF typ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ <br> Transition Time, $\mathrm{t}_{\text {transition }}$ <br> Break-Before-Make Time Delay, to <br> Charge Injection, Qinj <br> Off Isolation <br> Channel-to-Channel Crosstalk <br> Total Harmonic Distortion + Noise <br> -3 dB Bandwidth <br> Insertion Loss <br> $\mathrm{C}_{\mathrm{s}}$ (Off) <br> $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{\mathrm{s}}(\mathrm{On})$ | $\begin{aligned} & 217 \\ & 260 \\ & 86 \\ & 130 \\ & -60 \\ & -80 \\ & 0.01 \\ & \\ & 190 \\ & -0.8 \\ & 12 \\ & 55 \\ & \hline \end{aligned}$ | 310 | $\begin{aligned} & 336 \\ & 45 \end{aligned}$ | ns typ ns max ns typ ns min pC typ dB typ dB typ \% typ <br> MHz typ dB typ pF typ pF typ | $\begin{aligned} & R_{L}=300 \Omega, C_{L}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} ; \text { see Figure } 27 \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \mathrm{~V}_{\mathrm{S}}=10 \mathrm{~V} \text {; see Figure } 28 \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF} \text {; see Figure } 29 \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see Figure } 24 \\ & R_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see Figure } 23 \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 15 \mathrm{~V} \mathrm{p}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz} ; \\ & \text { see Figure } 25 \\ & R_{\mathrm{L}}=50 \Omega, C_{\mathrm{L}}=5 \mathrm{pF} ; \text { see Figure } 26 \\ & R_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see Figure } 26 \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{mHz} \end{aligned}$ |
| POWER REQUIREMENTS ID Iss $\mathrm{V}_{\mathrm{DD}} / \mathrm{V}_{\mathrm{SS}}$ | $\begin{aligned} & 45 \\ & 55 \\ & 0.001 \end{aligned}$ |  | 70 <br> 1 $\pm 9 / \pm 22$ | $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> $\mu A$ typ <br> $\mu \mathrm{A}$ max <br> $V \min / V \max$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-16.5 \mathrm{~V} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { Digital inputs }=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \\ & \text { GND }=0 \mathrm{~V} \end{aligned}$ |

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## 土20 V DUAL SUPPLY

$\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-20 \mathrm{~V} \pm 10 \%, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 2.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range On Resistance, Ron |  |  | $V_{\text {DD }}$ to $V_{S S}$ | V |  |
|  | 12.5 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$; see Figure 22 |
|  | 14 | 18 | 22 | $\Omega$ max | $\mathrm{V}_{\mathrm{DD}}=+18 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-18 \mathrm{~V}$ |
| On-Resistance Match Between Channels, $\Delta$ Ron | 0.1 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}= \pm 15 \mathrm{~V}, \mathrm{l}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  |  |  |  |  |  |
|  | 0.8 | 1.3 | 1.4 | $\Omega$ max |  |
| On-Resistance Flatness, Rflat (on) | 2.3 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}= \pm 15 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  | 2.7 | 3.3 | 3.7 | $\Omega$ max |  |
| LEAKAGE CURRENTS <br> Source Off Leakage, Is (Off) |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=+22 \mathrm{~V}, \mathrm{~V}_{5 S}=-22 \mathrm{~V}$ |
|  | $\pm 0.1$ |  |  | nA typ | $\mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 15 \mathrm{~V}$; see Figure 21 |
|  | $\pm 0.25$ | $\pm 1$ | $\pm 10$ | nA max |  |
| Channel On Leakage, lo (On), Is (On) | $\pm 0.1$ |  |  | nA typ | $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}= \pm 15 \mathrm{~V}$; see Figure 21 |
|  | $\pm 0.4$ | $\pm 4$ | $\pm 10$ | $n A \max$ |  |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, $\mathrm{V}_{\text {INH }}$ |  |  | 2.0 | $\checkmark$ min | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {dD }}$ |
| Input Low Voltage, $\mathrm{V}_{1 \times 1}$ |  |  | 0.8 | $\checkmark$ max |  |
| Input Current, $\mathrm{linL}_{\text {or }}$ or $\mathrm{linh}^{\text {and }}$ | 0.002 |  |  | $\mu A$ typ |  |
|  |  |  | $\pm 0.1$ | $\mu \mathrm{A}$ max |  |
| Digital Input Capacitance, CIN | 6 |  |  | pF typ |  |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ |  |  |  |  |  |
| Transition Time, trpanstion | 200 | 279 | 294 | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  | 235 |  |  | ns max | $\mathrm{V}_{\mathrm{s}}=10 \mathrm{~V}$; see Figure 27 |
| Break-Before-Make Time Delay, $\mathrm{t}_{\mathrm{D}}$ | 77 |  |  | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  |  |  | 46 | ns min | $\mathrm{V}_{\mathrm{s}}=10 \mathrm{~V}$; see Figure 28 |
| Charge Injection, Qin | 160 |  |  | pC typ | $\mathrm{V}_{S}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{L}=1 \mathrm{nF}$; see Figure 29 |
| Off Isolation | -60 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see Figure 24 |
| Channel-to-Channel Crosstalk | -80 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see Figure 23 |
| Total Harmonic Distortion + Noise | 0.01 |  |  | \% typ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 20 \mathrm{Vp}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz} ; \\ & \text { see Figure } 25 \end{aligned}$ |
| -3 dB Bandwidth | 190 |  |  | MHz typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 26 |
| Insertion Loss | -0.7 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see Figure 26 |
| $\mathrm{C}_{5}$ (Off) | 11 |  |  | pF typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{5}(\mathrm{On})$ | 55 |  |  | pF typ | $\mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=+22 \mathrm{~V}, \mathrm{~V}_{5 S}=-22 \mathrm{~V}$ |
| lod | 50 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\text {D }}$ |
|  | 70 |  | 110 | $\mu \mathrm{A}$ max |  |
| Iss | 0.001 |  |  | $\mu A \operatorname{typ}$ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
|  |  |  | 1 | $\mu \mathrm{A}$ max |  |
| $\mathrm{V}_{\text {DD }} / \mathrm{V}_{\text {SS }}$ |  |  | $\pm 9 / \pm 22$ | $\checkmark$ min $/ V$ max | $\mathrm{GND}=0 \mathrm{~V}$ |

[^1]
## 12 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 3.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | 0 V to $\mathrm{V}_{\mathrm{DD}}$ | V |  |
| On Resistance, Ron | 26 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} \text {; see }$ Figure 22 |
|  | 30 | 38 | 44 | $\Omega$ max | $\mathrm{V}_{\mathrm{DD}}=10.8 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ |
| On-Resistance Match Between Channels, $\Delta$ Ron | 0.1 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  | 1 | 1.5 | 1.6 | $\Omega$ max |  |
| On-Resistance Flatness, Rflat (on) | 5.5 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  | 6.8 | 8.3 | 12.3 | $\Omega$ max |  |
| LEAKAGE CURRENTS Source Off Leakage, Is (Off) |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=+13.2 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=0 \mathrm{~V}$ |
|  | $\pm 0.1$ |  |  | nA typ | $\mathrm{V}_{\mathrm{S}}=1 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=10 \mathrm{~V} \text { to } 1 \mathrm{~V} \text {; }$ see Figure 21 |
|  | $\pm 0.25$ | $\pm 1$ | $\pm 10$ | $n A \max$ |  |
| Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On})$, $\mathrm{I}_{5}(\mathrm{On})$ | $\pm 0.1$ |  |  | nA typ | $\mathrm{V}_{S}=\mathrm{V}_{\mathrm{D}}=1 \mathrm{~V}$ to 10 V ; see Figure 21 |
|  | $\pm 0.4$ | $\pm 4$ | $\pm 10$ | $n A$ max |  |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, V ${ }_{\text {INH }}$ |  |  | 2.0 | $\checkmark$ min | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
| Input Low Voltage, $\mathrm{V}_{\text {INL }}$ | 0.002 |  | 0.8 | $V$ max |  |
| Input Current, linl or linh |  |  |  | $\mu \mathrm{A}$ typ |  |
|  |  |  | $\pm 0.1$ | $\mu \mathrm{A}$ max |  |
| Digital Input Capacitance, $\mathrm{ClN}_{1 \mathrm{~N}}$ | 6 |  |  | pF typ |  |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ |  |  |  |  |  |
| Transition Time, ttransition | 333 | 508 | 567 | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  | 414 |  |  | ns max | $\mathrm{V}_{\mathrm{s}}=8 \mathrm{~V}$; see Figure 27 |
| Break-Before-Make Time Delay, $\mathrm{t}_{\mathrm{D}}$ | 176 |  |  | nstyp | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  |  |  | 97 | ns min | $\mathrm{V}_{s}=8 \mathrm{~V}$; see Figure 28 |
| Charge Injection, Qins | 55 |  |  | pC typ | $\mathrm{V}_{\mathrm{S}}=6 \mathrm{~V}, \mathrm{R}_{\mathrm{s}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}$; see Figure 29 |
| Off Isolation | -60 |  |  | dB typ | $\mathrm{RL}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see }$ $\text { Figure } 24$ |
| Channel-to-Channel Crosstalk | -80 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see }$ Figure 23 |
| Total Harmonic Distortion + Noise | 0.03 |  |  | \% typ | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 6 \mathrm{~V} \mathrm{p}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz} \text { to }$ $20 \text { kHz; see Figure } 25$ |
| -3 dB Bandwidth | 170 |  |  | MHz typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, C_{L}=5 \mathrm{pF}$; see Figure 26 |
| Insertion Loss | -1.7 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; see }$ $\text { Figure } 26$ |
| $\mathrm{C}_{s}$ (Off) | 15 |  |  | pF typ | $\mathrm{V}_{\mathrm{s}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{S}(\mathrm{On})$ | 50 |  |  | pF typ | $\mathrm{V}_{\mathrm{s}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS IDD | $\begin{aligned} & 40 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & 65 \\ & 9 / 40 \end{aligned}$ |  | $\mathrm{V}_{\mathrm{DD}}=13.2 \mathrm{~V}$ |
|  |  |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\text {DD }}$ |
|  |  |  |  | $\mu \mathrm{A}$ max |  |
| $V_{D D}$ |  |  |  | $\checkmark$ min $/ V$ max | $\mathrm{GND}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{ss}}=0 \mathrm{~V}$ |

[^2]
## 36 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 4.

| Parameter | $25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | 0 V to $\mathrm{V}_{\mathrm{DD}}$ | V |  |
| On Resistance, Ron | 14.5 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V} \text { to } 30 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} \text {; see }$ <br> Figure 22 |
|  | 16 | 20 | 24 | $\Omega$ max | $\mathrm{V}_{\mathrm{DD}}=32.4 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=0 \mathrm{~V}$ |
| On-Resistance Match Between Channels, $\Delta$ Ron | 0.1 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ to $30 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  |  |  |  |  |  |
|  | 0.8 | 1.3 | 1.4 | $\Omega$ max |  |
| On-Resistance Flatness, Rflat (on) | 3.5 |  |  | $\Omega \operatorname{typ}$ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ to $30 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  | 4.3 | 5.5 | 6.5 | $\Omega$ max |  |
| LEAKAGE CURRENTS Source Off Leakage, Is (Off) |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=39.6 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ |
|  | $\pm 0.1$ |  |  | nA typ | $\begin{aligned} & V_{S}=1 \mathrm{~V} \text { to } 30 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=30 \mathrm{~V} \text { to } 1 \mathrm{~V} \text {; } \\ & \text { see Figure } 21 \end{aligned}$ |
|  | $\pm 0.25$ | $\pm 1$ | $\pm 10$ | nA max |  |
| Channel On Leakage, $\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}$ ( $(O n)$ | $\pm 0.1$ |  |  | nA typ | $V_{S}=V_{D}=1 \mathrm{~V} \text { to } 30 \mathrm{~V} ;$ <br> see Figure 21 |
|  | $\pm 0.4$ | $\pm 4$ | $\pm 10$ | nA max |  |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, V INH |  |  | 2.0 | $V$ min |  |
| Input Low Voltage, $\mathrm{V}_{\text {INL }}$ |  |  | 0.8 | $\checkmark$ max |  |
| Input Current, I Ind or linh | 0.002 |  |  | $\mu \mathrm{A}$ typ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
|  |  |  | $\pm 0.1$ | $\mu \mathrm{A}$ max |  |
| Digital Input Capacitance, ClN | 6 |  |  | pF typ |  |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ |  |  |  |  |  |
| Transition Time, ttransition | 216 |  |  | ns typ | $\mathrm{RL}=300 \Omega, \mathrm{CL}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  | 250 | 286 | 310 | ns max | $\mathrm{V}_{\mathrm{s}}=18 \mathrm{~V}$; see Figure 27 |
| Break-Before-Make Time Delay, $\mathrm{t}_{\mathrm{D}}$ | 80 |  |  | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ |
|  |  |  | 47 | ns min | $\mathrm{V}_{5}=18 \mathrm{~V}$; see Figure 28 |
| Charge Injection, Qin | 135 |  |  | pC typ | $V_{s}=18 \mathrm{~V}, R_{S}=0 \Omega, C_{L}=1 \mathrm{nF}$; see Figure 29 |
| Off Isolation | -60 |  |  | dB typ | $R_{L}=50 \Omega, C_{L}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see Figure 24 |
| Channel-to-Channel Crosstalk | -80 |  |  | dB typ | $R \mathrm{~L}=50 \Omega, C_{L}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$; see Figure 23 |
| Total Harmonic Distortion + Noise | 0.01 |  |  | \% typ | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 18 \mathrm{~V}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz} \text { to }$ <br> 20 kHz ; see Figure 25 |
| -3 dB Bandwidth | 170 |  |  | MHz typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 26 |
| Insertion Loss | -1 |  |  | dB typ | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} ;$ <br> see Figure 26 |
| $\mathrm{C}_{5}$ (Off) | 14 |  |  | pF typ | $\mathrm{V}_{\mathrm{s}}=18 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{\mathrm{s}}(\mathrm{On})$ | 50 |  |  | pF typ | $\mathrm{V}_{\mathrm{S}}=18 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS IDD |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=39.6 \mathrm{~V}$ |
|  | 80 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
|  | 100 |  | 130 | $\mu \mathrm{A}$ max |  |
| $V_{D D}$ |  |  | 9/40 | $V$ min $/ V$ max | $\mathrm{GND}=0 \mathrm{~V}, \mathrm{~V}_{s \mathrm{~s}}=0 \mathrm{~V}$ |

[^3]
#### Abstract

Data Sheet ADG5419


## CONTINUOUS CURRENT PER CHANNEL, Sx OR D

Table 5.

| Parameter | $\mathbf{2 5}{ }^{\circ} \mathbf{C}$ | $\mathbf{8 5}^{\circ} \mathbf{C}$ | $\mathbf{1 2 5}{ }^{\circ} \mathbf{C}$ | Unit | Test Conditions/Comments |
| :--- | :--- | :--- | :--- | :--- | :--- |
| CONTINUOUS CURRENT, Sx OR D |  |  |  |  | MSOP $\left(\theta_{\mathrm{JA}}=133.1^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| $\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V}, \mathrm{~V}_{S S}=-15 \mathrm{~V}$ | 113 | 73 | 46 | mA maximum |  |
| $\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V}, \mathrm{~V}_{S S}=-20 \mathrm{~V}$ | 118 | 76 | 47 | mA maximum |  |
| $\mathrm{V}_{D D}=12 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ | 90 | 60 | 41 | mA maximum |  |
| $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ | 116 | 74 | 46 | mA maximum |  |

## ABSOLUTE MAXIMUM RATINGS

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.
Table 6.

| Parameter | Rating |
| :---: | :---: |
| $\mathrm{V}_{\text {DD }}$ to $\mathrm{V}_{\text {SS }}$ | 48 V |
| $V_{\text {DD }}$ to GND | -0.3 V to +48 V |
| $V_{\text {ss }}$ to GND | +0.3 V to -48 V |
| Analog Inputs ${ }^{1}$ | $V_{S S}-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V} \text { or } 30$ <br> mA , whichever occurs first |
| Digital Inputs ${ }^{1}$ | $\mathrm{V}_{S S}-0.3 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$ or 30 mA , whichever occurs first |
| Peak Current, Sx or D Pins | 410 mA (pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle maximum) |
| Continuous Current, Sx or D ${ }^{2}$ | Data + 15\% |
| Temperature Range |  |
| Operating | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Thermal Impedance, $\theta_{\mathrm{JA}}$ 8-Lead MSOP (4-Layer Board) | $133.1{ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Reflow Soldering Peak Temperature, Pb Free | As per JEDEC J-STD-020 |
| Human Body Model (HBM) ESD | 8 kV |

[^4]Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating can be applied at any one time.

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. <br> Charged devices and circuit boards can discharge <br> without detection. Although this product features <br> patented or proprietary protection circuitry, damage <br> may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to <br> avoid performance degradation or loss of functionality. |
| :--- | :--- |

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

| - | ADG5419 <br> TOP VIEW (Not to Scale) | 8 SB |
| :---: | :---: | :---: |
|  |  |  |
| SA 2 |  | $7^{\text {v }}$ ss |
| GND 3 |  | $6{ }^{10}$ |
| $\mathrm{V}_{\mathrm{DD}} 4$ |  | 5 NC |

## notes <br> 1. NC = NO CONNECT. NOT INTERNALLY CONNECTED. <br> 

Figure 2. Pin Configuration
Table 7. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | D | Drain Terminal. This pin can be an input or output. |
| 2 | SA | Source Terminal. This pin can be an input or output. |
| 3 | GND | Ground (0 V) Reference. |
| 4 | VDD | Most Positive Power Supply Potential. |
| 5 | NC | No Connect. Not internally connected. |
| 6 | IN | Logic Control Input. |
| 7 | VSS | Most Negative Power Supply Potential. |
| 8 | SB | Source Terminal. This pin can be an input or output. |

Table 8. Truth Table

| IN | Switch A | Switch B |
| :--- | :--- | :--- |
| 0 | On | Off |
| 1 | Off | On |

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 3. On Resistance as a Function of $V_{S}, V_{D}$ Dual Supply)


Figure 4. On Resistance as a Function of $V_{S}, V_{D}$ Dual Supply)


Figure 5. On Resistance as a Function of $V_{S}, V_{D}$ (Single Supply)


Figure 6. On Resistance as a Function of $V_{S}, V_{D}$ (Single Supply)


Figure 7. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, $\pm 15$ V Dual Supply


Figure 8. On Resistance as a Function of $V_{s}\left(V_{D}\right)$ for Different Temperatures, $\pm 20$ V Dual Supply


Figure 9. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, 12 V Single Supply


Figure 10. On Resistance as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, 36 V Single Supply


Figure 11. Leakage Currents as a Function of Temperature, $\pm 15$ V Dual Supply


Figure 12. Leakage Currents as a Function of Temperature, $\pm 20$ V Dual Supply


Figure 13. Leakage Currents as a Function of Temperature, 12 V Single Supply


Figure 14. Leakage Currents as a Function of Temperature, 36 V Single Supply


Figure 15. Off Isolation vs. Frequency


Figure 16. Crosstalk vs. Frequency


Figure 17. Charge Injection vs. Source Voltage


Figure 18. $T H D+N$ vs. Frequency


Figure 19. Bandwidth


Figure 20. $t_{\text {TRANSITION }}$ Times vs. Temperature

## Data Sheet

## TEST CIRCUITS



Figure 21. On and Off Leakage


Figure 22. On Resistance


Figure 23. Channel-to-Channel Crosstalk


Figure 24. Off Isolation


Figure 25. THD + Noise


Figure 26. Bandwidth


Figure 27. Switching Timing


Figure 28. Break-Before-Make Delay, $t_{D}$


Figure 29. Charge Injection

## TERMINOLOGY

## $I_{D D}$

IDD represents the positive supply current.
Iss
Iss represents the negative supply current.
$\mathbf{V}_{\mathrm{D}}, \mathrm{V}_{\mathrm{s}}$
$V_{D}$ and $V_{S}$ represent the analog voltage on Terminal $D$ and Terminal S, respectively.
Ron
Ron is the ohmic resistance between Terminal D and Terminal S.
$\Delta \mathbf{R}_{\text {ON }}$
$\Delta \mathrm{R}_{\mathrm{ON}}$ represents the difference between the R $\mathrm{R}_{\mathrm{ON}}$ of any two channels.
$\mathrm{R}_{\text {flat (ON) }}$
The difference between the maximum and minimum value of on resistance as measured over the specified analog signal range is represented by $\mathrm{R}_{\mathrm{FLAT} \text { (ON) }}$.
$I_{s}$ (Off)
Is (Off) is the source leakage current with the switch off.
$\mathrm{I}_{\mathrm{D}}(\mathbf{O n}), \mathrm{I}_{\mathrm{S}}(\mathbf{O n})$
$\mathrm{I}_{\mathrm{D}}(\mathrm{On})$ and $\mathrm{I}_{\mathrm{S}}(\mathrm{On})$ represent the channel leakage currents with the switch on.
VinL
$\mathrm{V}_{\text {INL }}$ is the maximum input voltage for Logic 0 .
Vinh
$\mathrm{V}_{\text {INH }}$ is the minimum input voltage for Logic 1.
Int, $\mathbf{I}_{\text {INH }}$
IINL and INH represent the low and high input currents of the digital inputs.

Cs (Off)
$\mathrm{C}_{s}$ (Off) represents the off switch source capacitance, which is measured with reference to ground.
$\mathrm{C}_{\mathrm{D}}$ (On), Cs(On)
$\mathrm{C}_{\mathrm{D}}(\mathrm{On})$ and $\mathrm{C}_{s}(\mathrm{On})$ represent on switch capacitances, which are measured with reference to ground.
$\mathrm{C}_{\mathrm{IN}}$
$\mathrm{C}_{\text {IN }}$ represents digital input capacitance.
$\mathbf{t}_{\text {transition }}$
Delay time between the $50 \%$ and $90 \%$ points of the digital inputs and the switch on condition when switching from one address state to another.
$t_{\text {D }}$
$t_{\text {D }}$ represents the off time measured between the $80 \%$ point of both switches when switching from one address state to another.

## Off Isolation

Off isolation is a measure of unwanted signal coupling through an off channel.

## Charge Injection

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

## Crosstalk

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

## Bandwidth

Bandwidth is the frequency at which the output is attenuated by 3 dB , from its dc level.

Total Harmonic Distortion + Noise (THD + N) The ratio of the harmonic amplitude plus noise of the signal to the fundamental is represented by THD +N .

## APPLICATIONS INFORMATION

The ADG54xx family of switches and multiplexers provide a robust solution for instrumentation, industrial, aerospace, and other harsh environments that are prone to latch-up, which is an undesirable high current state that can lead to device failure and persists until the power supply is turned off. The ADG5419 high voltage switch allows single-supply operation from 9 V to 40 V and dual-supply operation from $\pm 9 \mathrm{~V}$ to $\pm 22 \mathrm{~V}$. The ADG5419 (as well as other select devices within this family) achieves an 8 kV human body model ESD rating, which provides a robust solution, eliminating the need for separate protection circuitry designs in some applications.

## TRENCH ISOLATION

In the ADG5419, an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction-isolated switches, are eliminated, and the result is a completely latch-up immune switch.
In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. The two transistors form a silicon-controlled rectifier (SCR) type circuit, causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latch-up immune switch.


Figure 30. Trench Isolation

## Data Sheet

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA
Figure 31. 8-Lead Mini Small Outline Package [MSOP] (RM-8)
Dimensions shown in millimeters

## ORDERING GUIDE

| Model $^{1}$ | Temperature Range | Package Description | Package Option | Branding |
| :--- | :--- | :--- | :--- | :--- |
| ADG5419BRMZ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead Mini Small Outline Package $[\mathrm{MSOP}]$ | RM-8 | S 48 |
| ADG5419BRMZ-RL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead Mini Small Outline Package $[\mathrm{MSOP}]$ | RM-8 | S 48 |

[^5]NOTES
$\square$ Data Sheet

NOTES

## NOTES


[^0]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^1]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^2]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^3]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^4]:    ${ }^{1}$ Overvoltages at the IN, Sx, and D pins are clamped by internal diodes. Limit current to the maximum ratings given.
    ${ }^{2}$ See Table 5.

[^5]:    ${ }^{1} \mathrm{Z}=$ RoHS Compliant Part

